## **Development of an Arcless DC Circuit Breaker using a Mechanical Contact and a Semiconductor Device**

## Summary

Direct current circuit breakers (DCCBs) have receive considerable attention due to their increasing demand in DC power transmission and distributed generation. A hybrid DCCB comprising a mechanical contact, semiconductor device (SiC-MOSFET), and metal oxide varistor offers a small contact resistance when the mechanical contact is closed. After opening the mechanical contact, the contact voltage increases because a molten metal -bridge is formed between the contacts as a result of joule heating. This molten-bridge voltage promotes the current commutation from the mechanical contact to the SiC-MOSFET. After the current commutation is completed, a fast current interruption can be achieved by turning off the SiC-MOSFET. Therefore, the hybrid DCCB can achieve both a small contact resistance and a fast current interruption. We performed DC current (300 V-150 A) interruption experiment, and succeeded in obtaining arcless current interruption with a probability of 100%.







Our object is development of an arcless hybrid DCCB

## **Experimental setup**





2-pole W contacts

Boiling voltage 2Vb=4.2V





## **Results and Discussions**





Current



Piezo actuator

- Peak displacement 400 µm
- Capacitance 12.5 µF
- Generative force 170N
- Open time 1.5 mS